



Vishay General Semiconductor

Dual Common-Cathode High-Voltage Schottky Rectifier

Low Leakage Current 5.0 μA



| SB20 | 1 0H1500 | 2 3 CT-1 |
|----------|-------------|-------------|
| PIN 1 O- | — | PIN 2 |
| PIN 3 O | — | CASE |
| | | |

| PRIMARY CHARACTERISTICS | | | | | |
|-------------------------|----------|--|--|--|--|
| I _{F(AV)} | 2 x 10 A | | | | |
| V _{RRM} | 150 V | | | | |
| I _{FSM} | 200 A | | | | |
| V _F | 0.75 V | | | | |
| T _J | 175 °C | | | | |

FEATURES

• Guardring for overvoltage protection



• Low power loss, high efficiency



Low forward voltage drop

RoHS

High frequency operation

Solder dip 260 °C, 40 s

 Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

TYPICAL APPLICATIONS

For use in high frequency inverters, freewheeling and polarity protection applications.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, TO-262AA Epoxy meets UL 94V-0 flammability rating

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD22-B102

E3 suffix for consumer grade, meets JESD 201 class

1A whisker test

Mounting Torque: 10 in-lbs maximum

Polarity: As marked

| PARAMETER | SYMBOL | MBR20H150CT | UNIT |
|--|-----------------------------------|---------------|------|
| Maximum repetitive peak reverse voltage | V _{RRM} | 150 | V |
| Working peak reverse voltage | V _{RWM} | 150 | V |
| Maximum DC blocking voltage | V _{DC} | 150 | V |
| Maximum average forward rectified current total device per diode | I _{F(AV)} | 20 10 | А |
| Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode | I _{FSM} | 200 | А |
| Peak repetitive reverse current per diode at $t_p = 2 \mu s$, 1 kHz | I _{RRM} | 1.0 | А |
| Peak non-repetitive reverse surge energy per diode (8/20 μs waveform) | E _{RSM} | 10 | mJ |
| Non-repetitive avalanche energy per diode at 25 °C, I _{AS} = 1.5 A, L = 10 mH | E _{AS} | 11.25 | mJ |
| Voltage rate of change (rated V _R) | dV/dt | 10 000 | V/µs |
| Operating junction and storage temperature range | T _J , T _{STG} | - 65 to + 175 | °C |
| Isolation voltage (ITO-220AB only) from terminals to heatsink t = 1 min | V _{AC} | 1500 | V |

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MBR20H150CT, MBRF20H150CT & SB20H150CT-1

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| ELECTRICAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted) | | | | | | |
|---|---|---|----------------|------------------------------|----------|--|
| PARAMETER | TEST CONDITIONS | | SYMBOL | VALUE | UNIT | |
| Maximum instantaneous forward voltage per diode ⁽¹⁾ | $I_F = 10 \text{ A}$ $I_F = 10 \text{ A}$ $I_F = 20 \text{ A}$ $I_F = 20 \text{ A}$ | $T_{C} = 25 ^{\circ}\text{C}$ $T_{C} = 125 ^{\circ}\text{C}$ $T_{C} = 25 ^{\circ}\text{C}$ $T_{C} = 125 ^{\circ}\text{C}$ | V _F | 0.90 0.75 0.99 0.86 | V | |
| Maximum reverse current per diode at working peak reverse voltage (1) | | T _J = 25 °C T _J = 125 °C | I _R | 5.0 1.0 | μA mA | |

Note:

(1) Pulse test: 300 μ s pulse width, 1 % duty cycle

| THERMAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted) | | | | | |
|---|----------------|-----|------|------|------|
| PARAMETER | SYMBOL | MBR | MBRF | MBRB | UNIT |
| Typical thermal resistance per diode | $R_{	heta JC}$ | 2.2 | 4.2 | 2.2 | °C/W |

| ORDERING INFORMATION (Example) | | | | | | | |
|--------------------------------|--------------------|-----------------|--------------|---------------|---------------|--|--|
| PACKAGE | PREFERRED P/N | UNIT WEIGHT (g) | PACKAGE CODE | BASE QUANTITY | DELIVERY MODE | | |
| TO-220AB | MBR20H150CT-E3/45 | 2.06 | 45 | 50/tube | Tube | | |
| ITO-220AB | MBRF20H150CT-E3/45 | 2.20 | 45 | 50/tube | Tube | | |
| TO-262AA | SB20H150CT-1E3/45 | 1.58 | 45 | 50/tube | Tube | | |

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

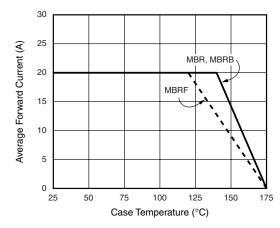


Figure 1. Forward Derating Curve (Total)

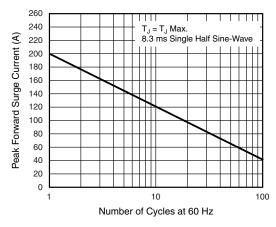


Figure 2. Maximum Non-Repetitive Peak Forward Surge Current Per Diode





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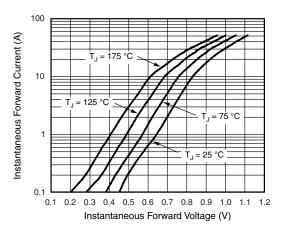


Figure 3. Typical Instantaneous Forward Characteristics Per Diode

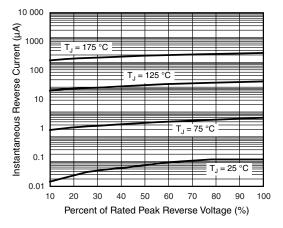


Figure 4. Typical Reverse Characteristics Per Diode

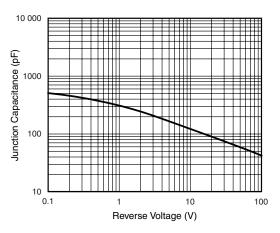


Figure 5. Typical Junction Capacitance Per Diode

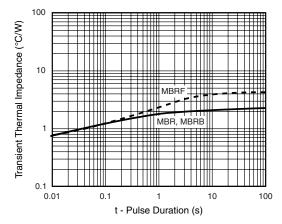


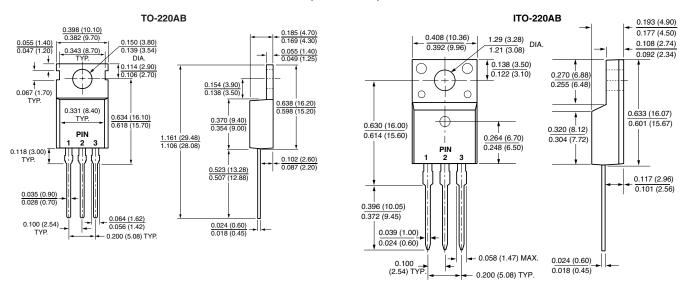
Figure 6. Typical Transient Thermal Impedance Per Diode

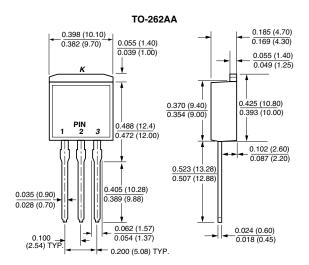
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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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